NSN 5962-01-351-9530

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Between 0.220 inches and 0.310 inches

Overall Height: 0.400 inches Body Length: 1.280 inches Body Width:



View Online at https://aerobasegroup.com/nsn/5962-01-351-9530

Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
1.1 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Satellite communications terminal an/usc-3 (v) 1	
Features Provided:	
Hermetically sealed and burn in and monolithic and programmed	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
22 input	
Case Outline Source And Designator:	
D-9 mil-m-38510	
Current Rating Per Characteristic:	
200.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Product Name:	
Registered and-or logic array	
Voltage Rating And Type Per Characteristic:	
-0.5 volts power source and 7.0 volts power source	
Time Rating Per Chacteristic:	
45.00 nanoseconds delay	
Memory Device Type:	
Pal	
Test Data Document:	
	s, individual manufactureer standards, etc.).

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Terminal Type A	and Quantity	/:
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0